NSN 5961-00-852-3110

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-852-3110 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 1.250 inches **Overall Diameter:** 0.105 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 60.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 80.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 80.0 milliwatts small-signal input power, common-collector preset **Precious Material And Location:** External surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release 3154 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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